

BTA/BTB06 Series

6A TRIACs

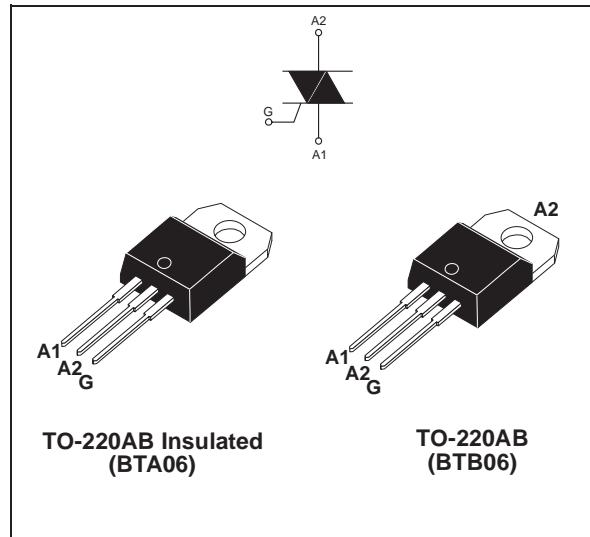
MAIN FEATURES:

Symbol	Value	Unit
$I_T(\text{RMS})$	6	A
$V_{\text{DRM}}/V_{\text{RRM}}$	600 and 800	V
$I_G(Q_1)$	5 to 50	mA

DESCRIPTION

Suitable for AC switching operations, the BTA/BTB06 series can be used as an ON/OFF function in applications such as static relays, heating regulation, induction motor starting circuits... or for phase control in light dimmers, motor speed controllers,...

The snubberless and logic level versions (BTA/BTB...W) are specially recommended for use on inductive loads, thanks to their high commutation performances. By using an internal ceramic pad, the BTA series provides voltage insulated tab (rated at 2500V RMS) complying with UL standards .



ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter			Value	Unit
$I_T(\text{RMS})$	RMS on-state current (full sine wave)		TO-220AB	6	A
			TO-220AB Ins.		
I_{TSM}	Non repetitive surge peak on-state current (full cycle, T_j initial = 25°C)		F = 50 Hz	60	A
			F = 60 Hz		
I^2t	I^2t Value for fusing		$t_p = 10 \text{ ms}$		A^2s
dl/dt	Critical rate of rise of on-state current $I_G = 2 \times I_{GT}$, $t_r \leq 100 \text{ ns}$	F = 120 Hz	$T_j = 125^\circ\text{C}$	50	$\text{A}/\mu\text{s}$
I_{GM}	Peak gate current	$t_p = 20 \mu\text{s}$	$T_j = 125^\circ\text{C}$	4	A
$P_{G(AV)}$	Average gate power dissipation			$T_j = 125^\circ\text{C}$	1 W
T_{stg} T_j	Storage junction temperature range Operating junction temperature range			- 40 to + 150 - 40 to + 125	°C

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ELECTRICAL CHARACTERISTICS (T_j = 25°C, unless otherwise specified)
■ SNUBBERLESS™ and LOGIC LEVEL (3 Quadrants)

Symbol	Test Conditions	Quadrant	BTA/BTB06				Unit	
			TW	SW	CW	BW		
I _{GT} (1)	V _D = 12 V R _L = 30 Ω	I - II - III	MAX.	5	10	35	50	mA
V _{GT}		I - II - III	MAX.	1.3				V
V _{GD}	V _D = V _{DRM} R _L = 3.3 kΩ T _j = 125°C	I - II - III	MIN.	0.2				V
I _H (2)	I _T = 100 mA		MAX.	10	15	35	50	mA
I _L	I _G = 1.2 I _{GT}	I - III	MAX.	10	25	50	70	mA
		II		15	30	60	80	
dV/dt (2)	V _D = 67 %V _{DRM} gate open T _j = 125°C	MIN.	20	40	400	1000	V/μs	
(dI/dt)c (2)	(dV/dt)c = 0.1 V/μs T _j = 125°C	MIN.	2.7	3.5	-	-	A/ms	
	(dV/dt)c = 10 V/μs T _j = 125°C		1.2	2.4	-	-		
	Without snubber T _j = 125°C		-	-	3.5	5.3		

■ STANDARD (4 Quadrants)

Symbol	Test Conditions	Quadrant	BTA/BTB06		Unit
			C	B	
I _G (1)	V _D = 12 V R _L = 30 Ω	I - II - III	MAX.	25	mA
V _{GT}		IV		50	
V _{GD}	V _D = V _{DRM} R _L = 3.3 kΩ T _j = 125°C	ALL	MIN.	0.2	
I _H (2)	I _T = 500 mA	ALL	MAX.	25	mA
I _L	I _G = 1.2 I _{GT}	I - III - IV	MAX.	40	mA
		II		80	
dV/dt (2)	V _D = 67 %V _{DRM} gate open T _j = 125°C	MIN.	200	400	V/μs
(dV/dt)c (2)	(dI/dt)c = 2.7 A/ms T _j = 125°C	MIN.	5	10	V/μs

STATIC CHARACTERISTICS

Symbol	Test Conditions			Value	Unit
V _T (2)	I _{TM} = 5.5 A t _p = 380 μs	T _j = 25°C	MAX.	1.55	V
V _{to} (2)	Threshold voltage	T _j = 125°C	MAX.	0.85	V
R _d (2)	Dynamic resistance	T _j = 125°C	MAX.	60	mΩ
I _{DRM}	V _{DRM} = V _{RRM}	T _j = 25°C	MAX.	5	μA
		T _j = 125°C		1	mA

Note 1: minimum IGT is guaranteed at 5% of IGT max.

Note 2: for both polarities of A2 referenced to A1

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Fig. 1: Maximum power dissipation versus RMS on-state current (full cycle).

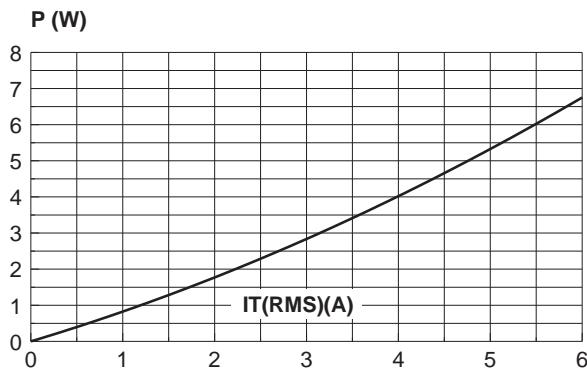


Fig. 3: Relative variation of thermal impedance versus pulse duration.

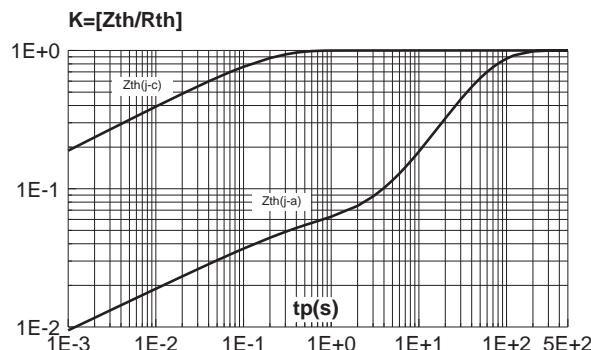


Fig. 5: Surge peak on-state current versus number of cycles.

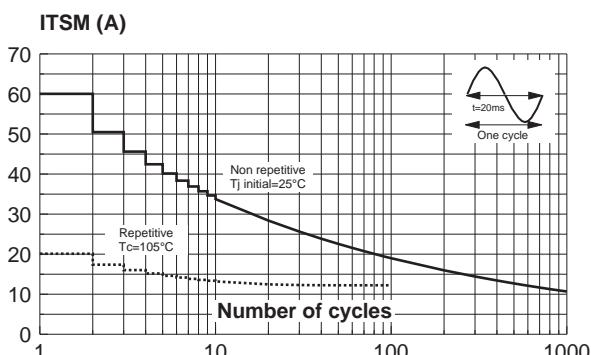


Fig. 2: RMS on-state current versus case temperature (full cycle).

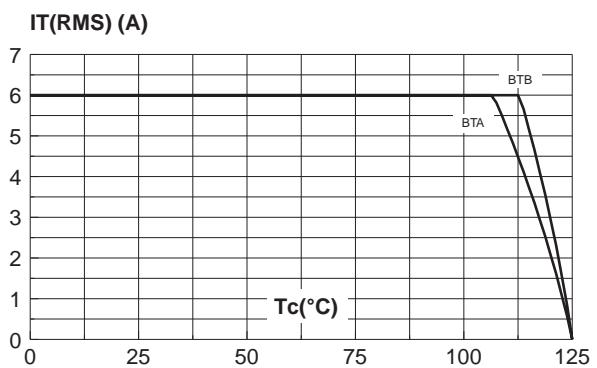


Fig. 4: On-state characteristics (maximum values).

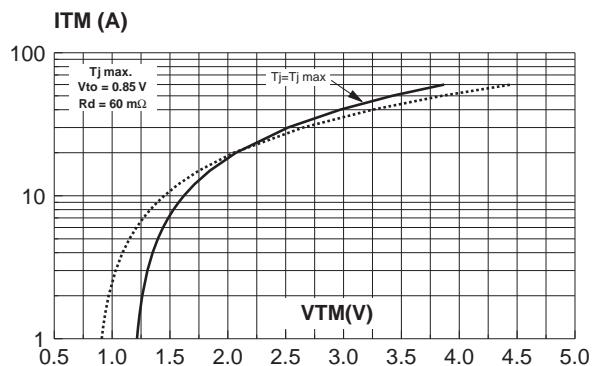
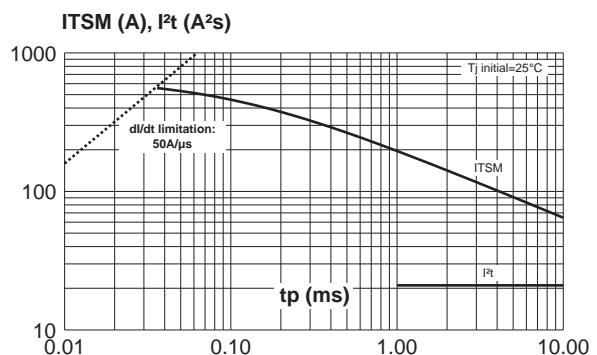


Fig. 6: Non-repetitive surge peak on-state current for a sinusoidal pulse with width $t_p < 10\text{ms}$, and corresponding value of I^2t .



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Fig. 7: Relative variation of gate trigger current, holding current and latching current versus junction temperature (typical values).

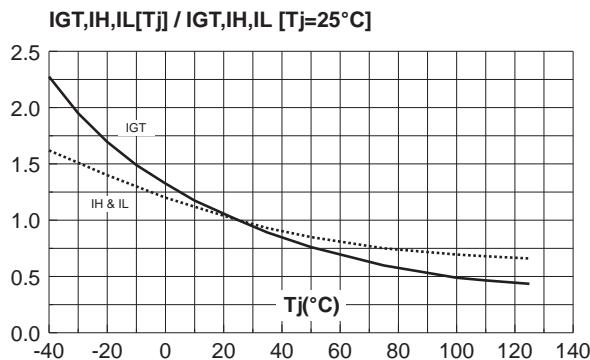


Fig. 8-2: Relative variation of critical rate of decrease of main current versus $(dV/dt)c$ (typical values). Standard Types

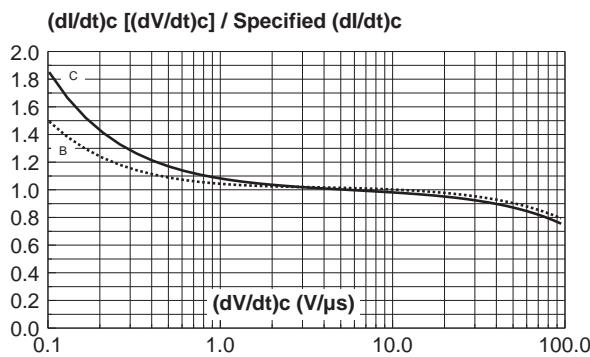


Fig. 8-1: Relative variation of critical rate of decrease of main current versus $(dV/dt)c$ (typical values). Snubberless & Logic Level Types

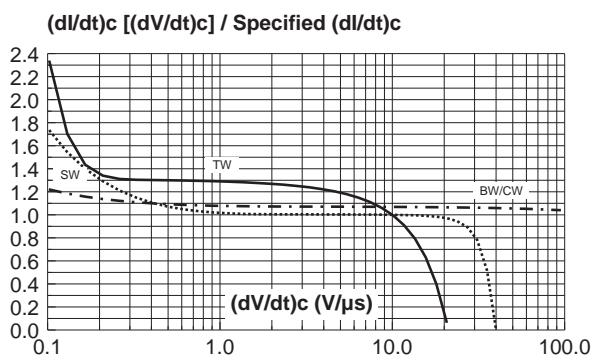


Fig. 9: Relative variation of critical rate of decrease of main current versus junction temperature.

